

# RL201 THRU RL207

### 2.0AMPS . SILICON RECTIFIER

### **FEATURE**

- . High current capability,
- . Low forward voltage drop
- . Low power loss, high efficiency
- . High surge capability
- . High temperature soldering guaranteed

260°C /1 0sec/0.375" lead length at 5 lbs tension

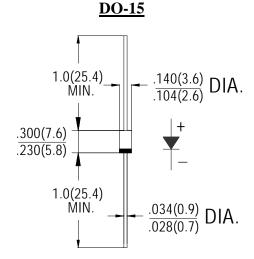
#### **MECHANICAL DATA**

. Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C

Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy

. Polarity: color band denotes cathode

. Mounting position: any



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

Type Number	SYM BOL	RL 201	RL 202	RL 203	RL 204	RL 205	RL 206	RL 207	units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at TA =75°C	$I_{F(AV)}$	$I_{F(AV)}$ 2.0							A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	$I_{FSM}$	60.0							A
Maximum Forward Voltage at 2.0A DC	$V_F$	1.0							V
Maximum DC Reverse Current $Ta = 25^{\circ}C$ at rated DC blocking voltage $Ta = 100^{\circ}C$	$I_R$	5.0 50.0							μА
Typical Junction Capacitance (Note 1)	Cj	<i>Cj</i> 30						pF	
Typical Thermal Resistance (Note 2)	$R_{(JA)}$	50							°C/W
Storage Temperature	$T_{STG}$								°C
Operation Junction Temperature	$T_J$	-55 to +125							°C

#### Note:

- 1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
- 2. Thermal Resistance from Junction to Ambient at 0.375" (9.5mm) lead length,

## RATING AND CHARACTERISTIC CURVES (RL201 THRU RL207)

